TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4066AP, TC74HC4066AF, TC74HC4066AFT

Quad Bilateral Switch

The TC74HC4066A is a high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C²MOS technology.

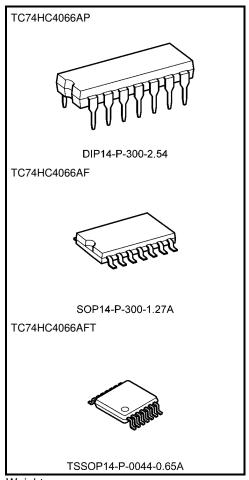
It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

Control input (C) is provided to control the switch. The switch turns ON while the C input is high, and the switch turns OFF while low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

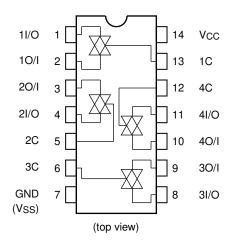
Low power dissipation: ICC = 1.0 μ A (max) at Ta = 25°C High noise immunity: VNIH = VNIL = 28% VCC (min) Low ON resistance: RON = 50 Ω (typ.) at VCC = 9 V High degree of linearity: THD = 0.05% (typ.) at VCC = 4.5 V Pin and function compatible with TC4066B series



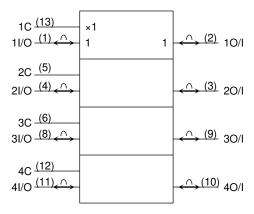
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

Pin Assignment



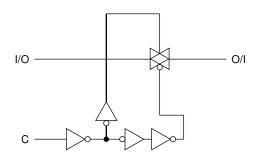
IEC Logic Symbol



Truth Table

Control	Switch Function
Н	On
L	Off

System diagram (Per Circuit)





Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 13	V
Control input voltage	VIN	-0.5 to V _{CC} + 0.5	V
Switch I/O voltage	V _{I/O}	-0.5 to V _{CC} + 0.5	V
Control input diode current	lıĸ	±20	mA
I/O diode current	II/OK	±20	mA
Switch through Current	lΤ	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 1)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	upply voltage V _{CC} 2 to 12		V
Control input voltage	VIN	0 to Vcc	V
Switch I/O voltage	V _{I/O}	0 to VCC	V
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	tr, tf	0 to 1000 (V _{CC} = 2.0 V)	
		0 to 500 (V _{CC} = 4.5 V)	no
		0 to 400 (V _{CC} = 6.0 V)	ns
		0 to 250 (V _{CC} = 10.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C		Unit		
2 market and a symbol		Tost condition	Vcc (V)	Min	Тур.	Max	Min	Max	Offic	
			2.0	1.50	_	_	1.50	_		
High-level control			4.5	3.15	_	_	3.15	_	.,	
input voltage	VIHC	_	9.0	6.30	_	_	6.30	_	V	
			12.0	8.40	_	_	8.40	_		
			2.0	_	_	0.50	_	0.50		
Low-level control	VILC		4.5	_	_	1.35	_	1.35	V	
input voltage	VILC	_	9.0	_	_	2.70	_	2.70	V	
			12.0	1	1	3.60	_	3.60		
		V _{IN} = V _{IHC}	4.5	_	96	170	_	200		
		$V_{I/O} = V_{CC}$ to GND	9.0	_	55	85	_	100		
		I _{I/O} ≤ 1 mA	12.0	_	45	80	_	90		
ON resistance	R _{ON}	$V_{IN} = V_{IHC}$ $V_{I/O} = V_{CC} \text{ or GND}$ $I_{I/O} \le 1 \text{ mA}$	2.0	_	160	_	_	_	Ω	
			4.5	_	70	100	_	130		
			9.0	_	50	75	_	95		
			12.0	_	45	70	_	90		
Difference of ON	ΔR _{ON}	V _{IN} = V _{IHC}	4.5	_	10	_	_	_		
resistance between		$V_{I/O} = V_{CC}$ to GND	9.0	_	5	_	_	_	Ω	
switches		I _{I/O} ≤ 1 mA	12.0	_	5	_	_	_		
Input/output leakage		V _{OS} = V _{CC} or GND								
current	IOFF	V _{IS} = GND or V _{CC}	12.0	_	_	±100	_	±1000	nA	
(switch off)		V _{IN} = V _{ILC}								
Switch input leakage current	1	V _{OS} =V _{CC} or GND	12.0			1100		11000	5 A	
(switch on, output open)	lız	VIN = VIHC	12.0	_	_	±100		±1000	nA	
Control input current	I _{IN}	V _{IN} = V _{CC} or GND	12.0	1	-	±100	_	±1000	nA	
			6.0	_	_	1.0	_	10.0		
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND	9.0	_	_	4.0	_	40.0	μΑ	
odironi			12.0	_	_	8.0	_	80.0		



AC Characteristics (CL = 50 pF, input: tr = tf = 6 ns)

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
J. J	- Cyco.	1 oot oonaliion	VCC (V)	Min	Тур.	Max	Min	Max	Orme
			2.0	_	10	50	_	65	ns
Phase difference between input and	ФІ-О		4.5	_	4	10	_	13	
output	ΨΙ-Ο	_	9.0	_	3	8	_	10	115
			12.0	-	3	7	_	9	
			2.0	_	18	100	_	125	
Output enable time	tpZL	$R_L = 1 k\Omega$	4.5	_	8	20	_	25	ns
Output enable time	t _p zH	C _L = 50 pF	9.0	_	6	12	_	22	113
			12.0	-	6	12	_	18	
			2.0	_	20	115	_	145	
Output disable time	tpLZ	$R_L = 1 k\Omega$	4.5	_	10	23	_	29	ns
Output disable time	t _{pHZ}	C _L = 50 pF	9.0	_	8	20	_	25	
			12.0	_	8	18	_	22	
		R _L = 1 kΩ	2.0	_	30	_	_	_	MHz
Maximum control		$C_L = 50 \text{ pF}$ $V_{OUT} = 1/2 \text{ V}_{CC}$	4.5	_	30	_	_	_	
input frequency			9.0	_	30	_	_	_	
		VOUT = 1/2 VCC	12.0	-	30	_	_	_	
Control input capacitance	C _{IN}	_		1	5	10	_	10	pF
Switch terminal capacitance	C _{I/O}	_		1	6	_	_	_	pF
Feed through capacitance	Cios	_			0.5				pF
Power dissipation capacitance	C _{PD}		(Note 1)	_	15		_	_	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = $CPD \cdot VCC \cdot fIN + ICC / 4$ (per channel)



Analog Switch Characteristics (Note) (GND = 0 V, Ta = 25°C)

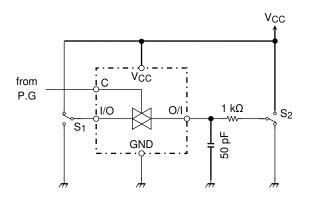
Characteristics	Symbol	Test Condition		Тур.	Unit
Sine wave distortion (T.H.D)		$\begin{split} f_{IN} &= 1 \text{ kHz}, V_{IN} = 4 V_{p\text{-}p}, @V_{CC} = 4.5 V \\ R_L &= 10 k\Omega, V_{IN} = 8 V_{p\text{-}p}, @V_{CC} = 9.0 V \\ C_L &= 50 pF \end{split}$	4.5 9.0	0.05 0.04	%
Frequency response (switch on)	f _{max}	$f_{max} \begin{tabular}{l} Adjust f_{IN} voltage to obtain 0dBm at V_{OS} \\ Increase f_{IN} frequency until dB meter reads -3dB \\ R_L = 50 \ \Omega, \ C_L = 10 \ pF \\ f_{IN} = 1 \ MHz, \ sine wave \\ \end{tabular}$		200 200	MHz
Feedthrough attenuation (switch off)		V_{IN} is centered at $V_{CC}/2$ Adjust input for 0dBm $R_L = 600 \ \Omega, \ C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$, sine wave	4.5 9.0	-60 -60	dB
Crosstalk (control input to signal output)		$R_L = 600 \ \Omega, \ C_L = 50 \ pF$ $f_{IN} = 1 \ MHz, \ square \ wave \ (t_r = t_f = 6 \ ns)$	4.5 9.0	60 100	mV
Crosstalk (between any switches)	Adjust V_{IN} to obtain 0dBm at input $R_L = 600~\Omega,~C_L = 50~pF$ $f_{IN} = 1~MHz,~sine~wave$		4.5 9.0	-60 -60	dB

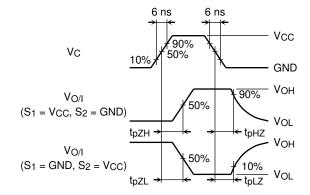
6

Note: These characteristics are determined by design of devices.

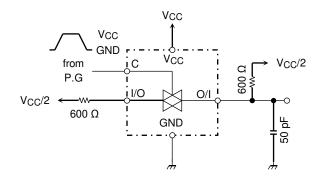
Switching Characteristics Test Circuits

1. tpLZ, tpHZ, tpZL, tpZH

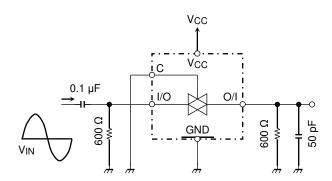




2. Cross Talk (control input-switch output) fin = 1 MHz duty = 50% tr = tf = 6 ns

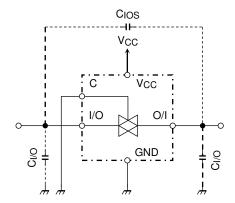


3. Feedthrough Attenuation

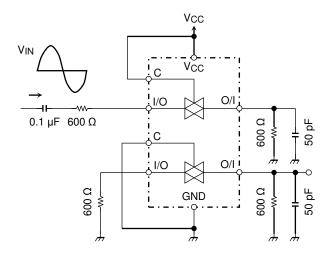




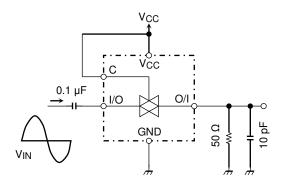
4. Cios, Ci/o



5. Crosstalk (between any two switches)

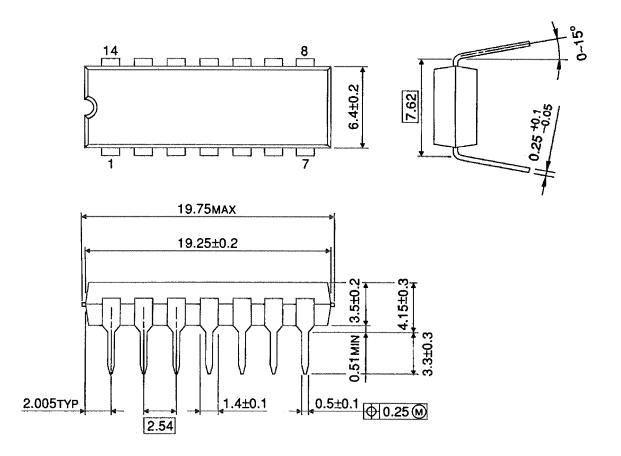


6. Frequency Response (switch on)



Package Dimensions

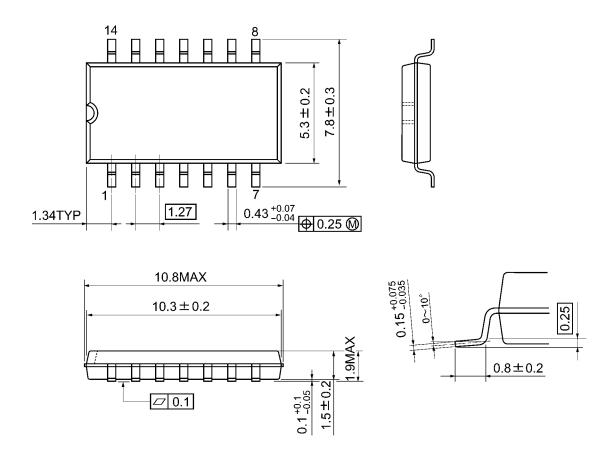
DIP14-P-300-2.54 Unit: mm



Weight: 0.96 g (typ.)

Package Dimensions

SOP14-P-300-1.27A Unit: mm



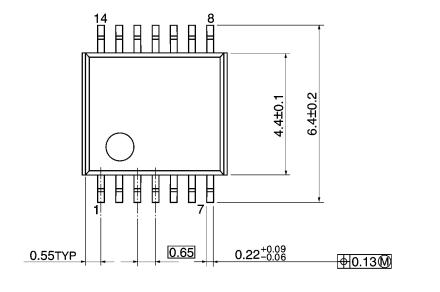
Weight: 0.18 g (typ.)

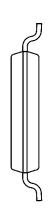


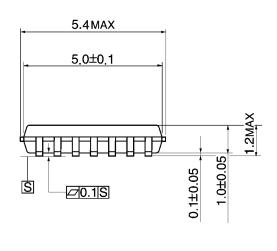
Package Dimensions

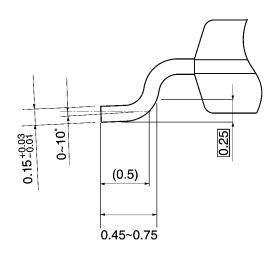
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
 automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
 safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative.
- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.